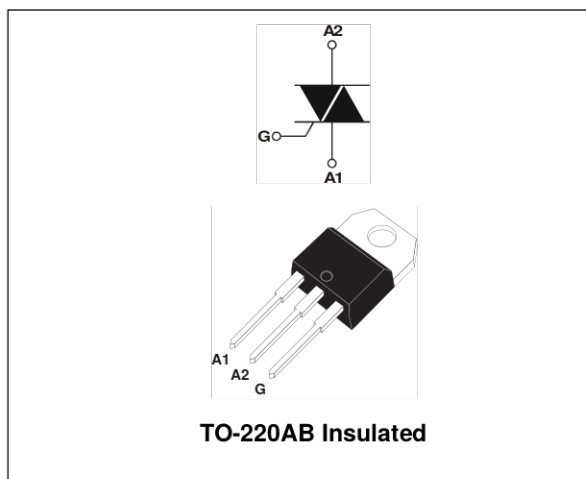


20 A Snubberless™ Triacs

Datasheet - production data

**Features**

- $I_{T(RMS)} = 20\text{ A}$
- $V_{DRM}, V_{RRM} = 600\text{ and }700\text{ V}$
- $I_{GT(Q1)}(\text{max}) = 35\text{ and }50\text{ mA}$

Description

The BTA20 Triacs use high performance glass passivated chip technology. The Snubberless concept offers suppression of the RC network and is suitable for applications such as phase control and static switching on inductive or resistive load.

Thanks to their clip assembly technique, the BTA20 Triacs provide a superior performance in surge current handling capabilities.

By using an internal ceramic pad, the BTA series provides voltage insulated tab (rated at 2500 V rms) complying with UL standards (File ref.: E81734).

TM: Snubberless is a trademark of STMicroelectronics.

1 Characteristics

Table 1. Absolute maximum ratings

Symbol	Parameter		Value	Unit	
$I_{T(RMS)}$	On-state rms current (full sine wave)		$T_c = 70\text{ °C}$	20	A
I_{TSM}	Non repetitive surge peak on-state current (full cycle, T_j initial = 25°C)	F = 50 Hz	t = 10 ms	210	A
		F = 60 Hz	t = 8.3 ms	200	
I^2t	I^2t Value for fusing	$t_p = 10\text{ ms}$		200	A ² s
dI/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $t_r \leq 100\text{ ns}$	Repetitive F = 50 Hz	$T_j = 125\text{ °C}$	50	A/μs
		Non repetitive		100	
V_{DSM} , V_{RSM}	Non repetitive peak off-state voltage	$t_p = 10\text{ ms}$	$T_j = 25\text{ °C}$	V_{DRM}/V_{RRM} 100	V
I_{GM}	Peak gate current	$t_p = 20\text{ μs}$	$T_j = 125\text{ °C}$	4	A
V_{GM}	Peak positive gate voltage	$t_p = 20\text{ μs}$		16	V
$P_{G(AV)}$	Average gate power dissipation		$T_j = 125\text{ °C}$	1	W
T_{stg}	Storage junction temperature range			- 40 to + 150	°C
T_j	Operating junction temperature range			- 40 to + 125	

Table 2. Electrical characteristics ($T_j = 25\text{ °C}$, unless otherwise specified)

Symbol	Test conditions	Quadrant		BTA20		Unit
				BW	CW	
$I_{GT}^{(1)}$	$V_D = 12\text{ V}$, $R_L = 33\text{ Ω}$	ALL	Min.	2	1	mA
			Max.	50	35	
V_{GT}		ALL	Max.	1.5		V
V_{GD}	$V_D = V_{DRM}$, $R_L = 3.3\text{ kΩ}$, $T_j = 125\text{ °C}$	ALL	Min.	0.2		V
$I_H^{(2)}$	$I_T = 500\text{ mA}$, gate open		Max.	75	50	mA
I_L	$I_G = 1.2 I_{GT}$	I - III	Typ.	50	-	mA
		II		90	-	
		I - II - III	Max.	-	80	
dV/dt ⁽²⁾	$V_D = 67\% V_{DRM}$, gate open	$T_j = 125\text{ °C}$	Typ.	750	500	V/μs
			Min.	500	250	
(dV/dt) _C ⁽²⁾	(dI/dt) _C = 20 A/ms	$T_j = 125\text{ °C}$	Typ.	36	22	V/μs
			Min.	18	11	

1. Minimum I_{GT} is guaranteed at 5% of I_{GT} max.

2. For both polarities of A2 referenced to A1.

Table 3. Static characteristics

Symbol	Parameter			Value	Unit
$V_{TM}^{(1)}$	$I_{TM} = 28 \text{ A}$, $t_p = 380 \mu\text{s}$	$T_j = 125 \text{ }^\circ\text{C}$	Max.	1.70	V
I_{DRM}	$V_{DRM} = V_{RRM}$	$T_j = 125 \text{ }^\circ\text{C}$	Max.	10	μA
I_{RRM}		$T_j = 125 \text{ }^\circ\text{C}$		3	mA

1. For both polarities of A2 referenced to A1.

Table 4. Thermal resistances

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	Junction to case for AC	2.1	$^\circ\text{C/W}$
$R_{th(j-c)}$	Junction to case for DC	2.8	
$R_{th(j-a)}$	Junction to ambient	60	

Figure 1. Maximum power dissipation versus on-state rms current (full cycle)

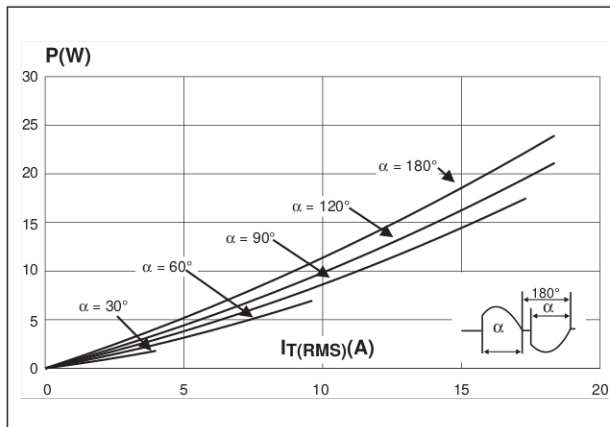


Figure 2. Correlation between maximum rms power dissipation and maximum allowable temperatures

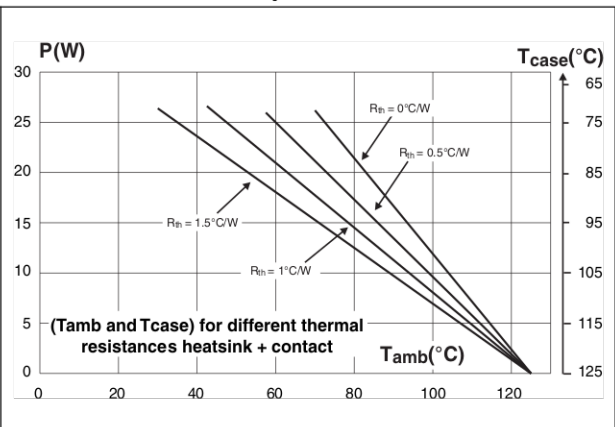


Figure 3. On-state rms current versus case temperature (full cycle)

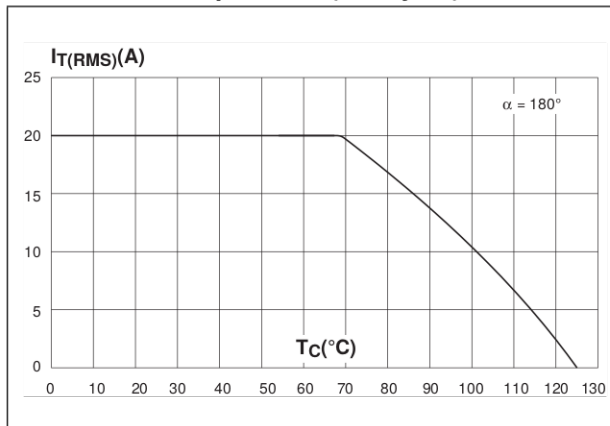


Figure 4. Relative variation of thermal impedance versus pulse duration

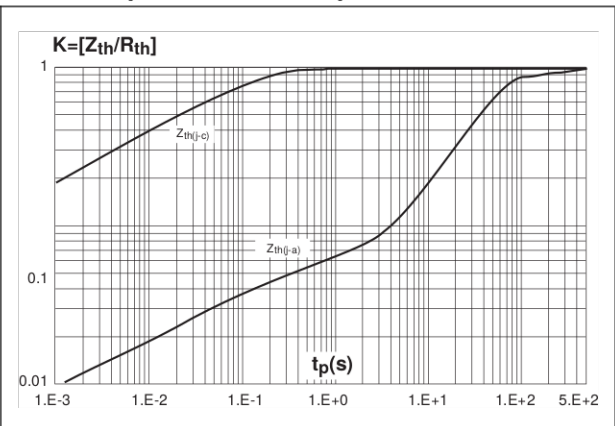


Figure 5. On-state characteristics (maximum values)

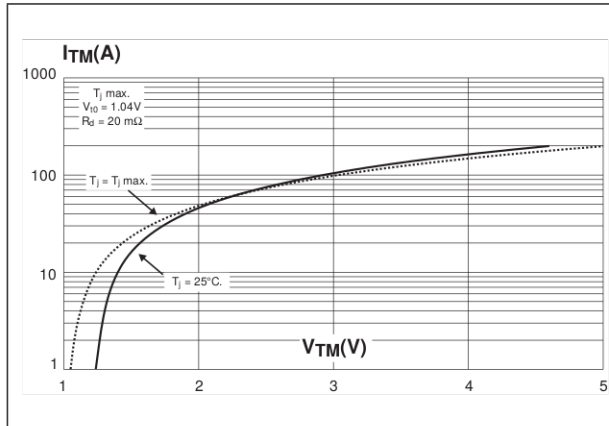


Figure 6. Non repetitive surge peak on-state current versus number of cycles

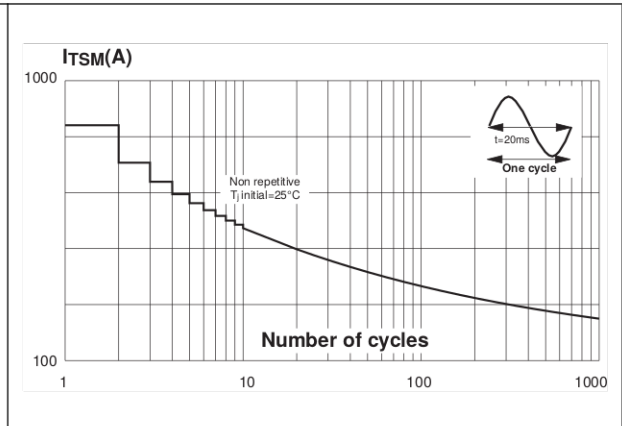


Figure 7. Non repetitive surge peak on-state current for a sinusoidal pulse and corresponding value of I^2t

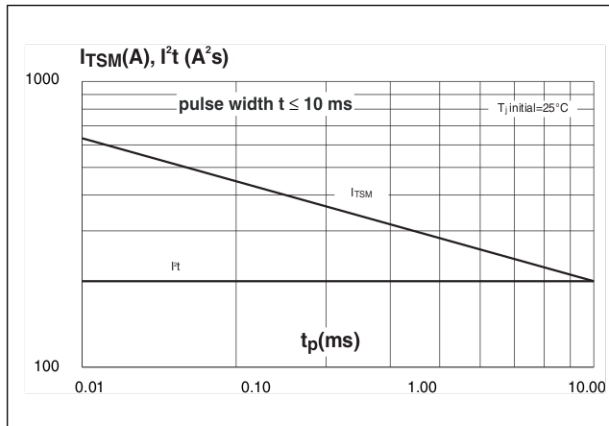
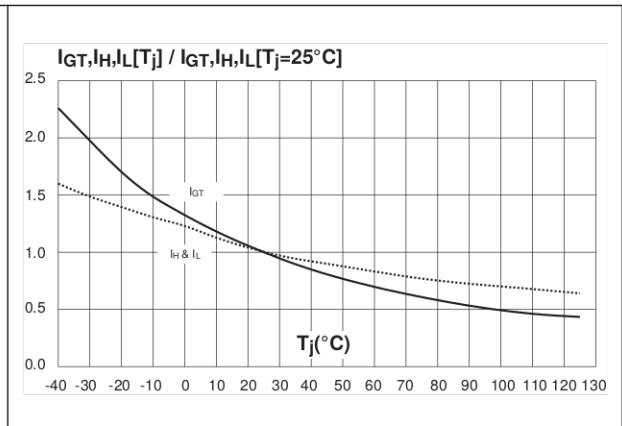


Figure 8. Relative variation of gate trigger current and holding current versus junction temperature



2 Package information

- Epoxy meets UL94, V0
- Lead-free package

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

Figure 9. TO-220AB package dimensions (definitions)

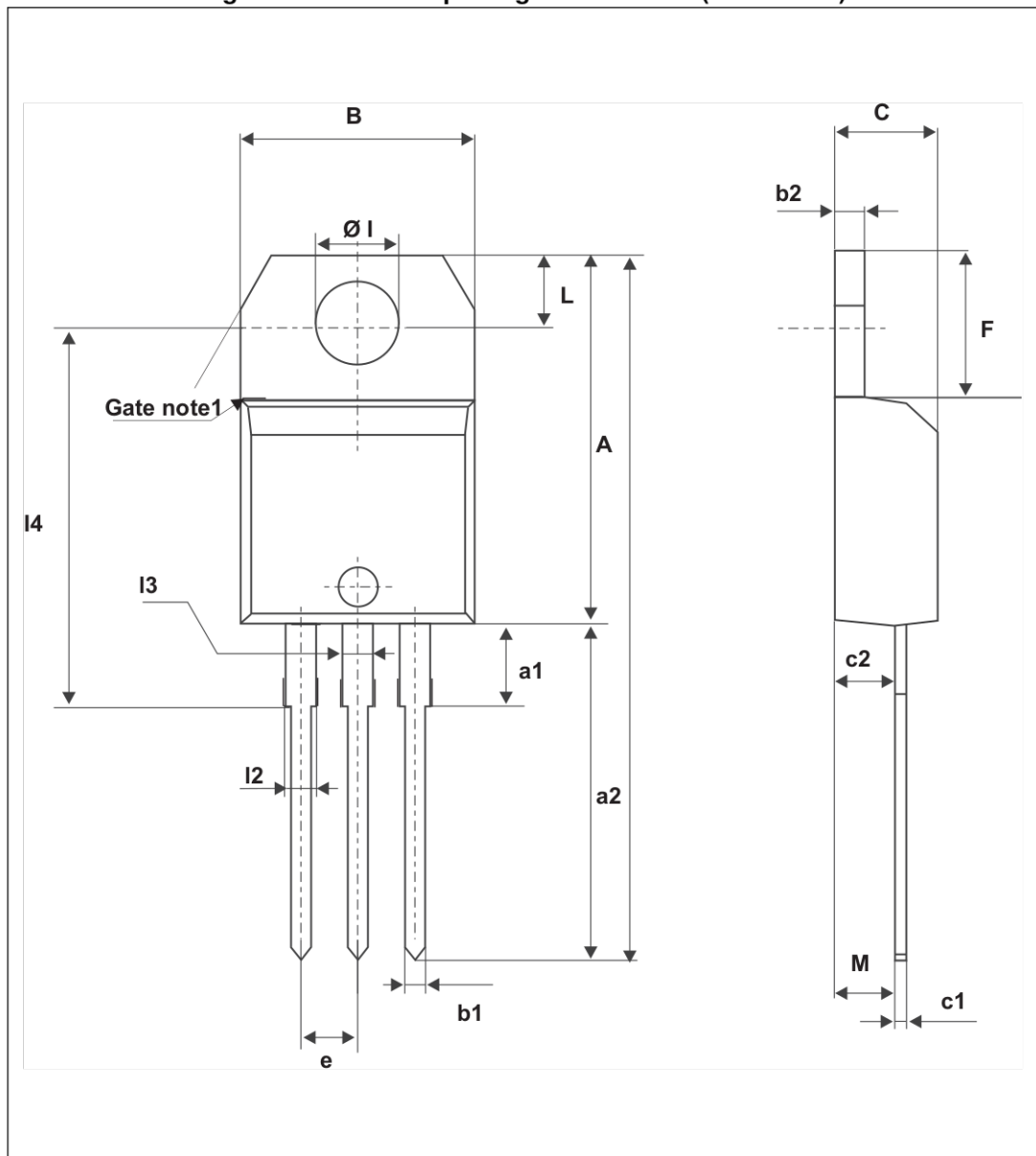


Table 5. TO-220AB package dimension values

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	15.20		15.90	0.598		0.625
a1		3.75			0.147	
a2	13.00		14.00	0.511		0.551
B	10.00		10.40	0.393		0.409
b1	0.61		0.88	0.024		0.034
b2	1.23		1.32	0.048		0.051
C	4.40		4.60	0.173		0.181
c1	0.49		0.70	0.019		0.027
c2	2.40		2.72	0.094		0.107
e	2.40		2.70	0.094		0.106
F	6.20		6.60	0.244		0.259
I	3.75		3.85	0.147		0.151
I4	15.80	16.40	16.80	0.622	0.646	0.661
L	2.65		2.95	0.104		0.116
I2	1.14		1.70	0.044		0.066
I3	1.14		1.70	0.044		0.066
M		2.60			0.102	

3 Ordering information

Figure 10. Ordering information scheme

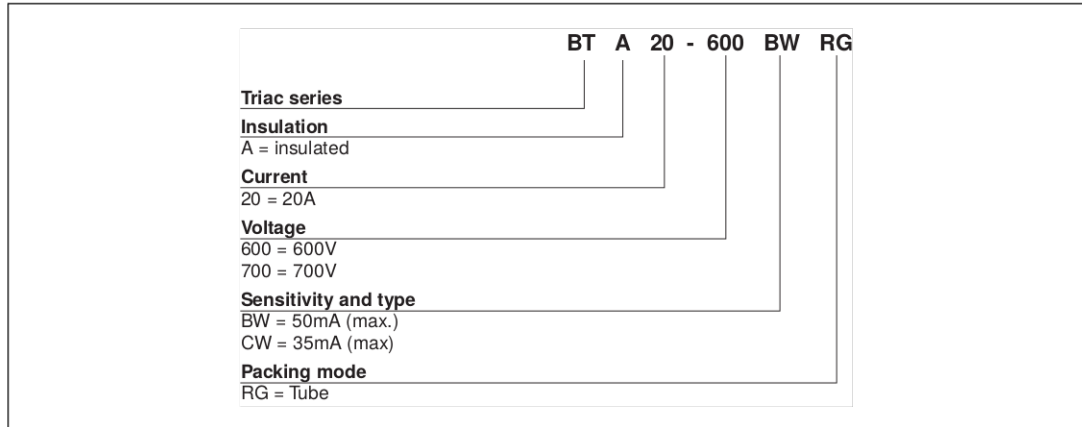


Table 6. Product selector

Order code	Voltage		Sensitivity	Type	Package
	600 V	700 V			
BTA20-600CWRG	X		35 mA	Snubberless	TO-220AB Ins.
BTA20-700BWRG		X	50 mA		
BTA20-700CWRG		X	35 mA		

Table 7. Ordering information

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
BTA20-600CWRG	BTA20-600CW	TO-220AB Ins.	2.3 g	50	Tube
BTA20-700BWRG	BTA20-700BW				
BTA20-700CWRG	BTA20-700CW				

4 Revision history

Table 8. Document revision history

Date	Revision	Changes
Sep-2001	1A	Initial release.
08-Feb-2006	2	TO-220AB Ins. delivery mode changed from bulk to tube.
09-Jul-2012	3	Updated di/dt repetitive value in Table 1 .
01-Sep-2014	4	Updated V_{DRM}/V_{RRM} value in Table 1 .

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